High Voltage LED Series Chip on Board

LCoogD – Gen.2



High efficacy COB LED package well-suited for use in spotlight applications









Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- · Simple assembly reduces manufacturing cost
- · Low thermal resistance
- InGaN/GaN MQW LED with long time reliability

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination

Table of Contents

1.	Characteristics	 3
2.	Product Code Information	 5
3.	Typical Characteristics Graphs	 8
4.	Outline Drawing & Dimension	 10
5.	Reliability Test Items & Conditions	 11
6.	Label Structure	 12
7.	Packing structure	 13
8.	Precautions in Handling & Use	 14

1. Characteristics

a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	°C	-
Storage Temperature	T_{stg}	-40 ~ +120	°C	-
LED Junction Temperature	TJ	150	°C	-
Case Temperature	Tc	115	°C	
Forward Current	l _F	690	mA	-
Power Dissipation	P_{D}	25.9	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

b) Electro-optical Characteristics ($I_F = 270 \text{ mA}, T_J = 85 \text{ }^{\circ}\text{C}$)

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V _F)	V	YZ	31.8	34.6	37.5
		3	70	-	-
Color Rendering Index (R _a)	-	5	80	-	-
		7	90		
Thermal Resistance (junction to case point)	°C/W		-	0.99	-
Beam Angle	0		-	115	-
Nominal Power	W			9.3	

Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_J = T_C = T_a = 85$ °C)
- 2) Samsungmaintains measurement tolerance of: forward voltage = ± 5 %, CRI = ± 1
- 3) Refer to the derating curve, '3. Typical Characteristics Graph'designed within the range.

c) Luminous Flux Characteristics (I_F = 270 mA)

CRI (R _a)	Nominal	Flux	Flux@ T _c = 85 °C (lm)			
Min.	CCT (K)	Rank	Min.	Тур.	Max.	
	3000	D2	1428	1503	-	
70	4000	D2	1497	1576	-	
	5000	D2	1545	1626	-	
	2700	D2	1275	1342	-	
	3000	D2	1347	1418	-	
	3500	D2	1386	1459	-	
80	4000	D2	1419	1494	-	
	5000	D2	1431	1506	-	
	5700	D2	1431	1506	-	
	6500	D2	1414	1488	-	
	2700	D2	1094	1152	-	
	3000	D2	1146	1206	-	
90	3500	D2	1182	1245	-	
	4000	D2	1209	1273	-	
	5000	D2	1214	1278	-	

Notes:

- 1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature $(T_J = T_C = 85 \, ^{\circ}C)$.
- 2) Samsungmaintains measurement tolerance of: Luminous flux = ± 7 %, CRI = ± 1

2. Product Code Information

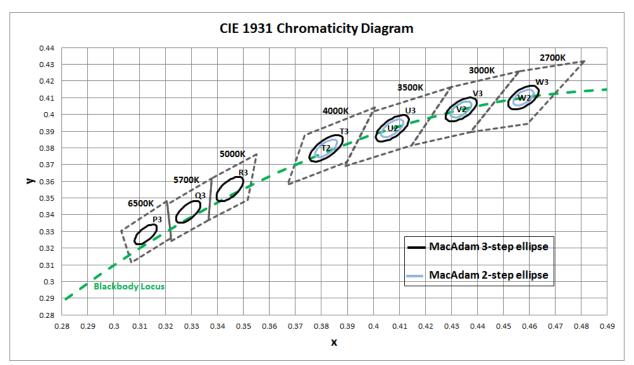
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	н	W	н	Α	н	D	N	С	2	5	Υ	Z	W	3	D	2

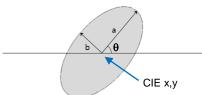
Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	Α	
7 8	Form Factor	HD	СОВ
9	Lens Type	N	No lens
10	Wattage or Model	С	LC009D
11	Internal Code	2	
		3	Min. 70 (85°C)
12	CRI & Sorting Temperature	5	Min. 80 (85°C)
		7	Min. 90 (85°C)
13 14	Forward Voltage (V)	YZ	31.8~37.5
		w	2700K
		V	3000K
		U	3500K
15	CCT (K)	Т	4000K
		R	5000K
		Q	5700K
		Р	6500K
16	MacAdam Step	2	MacAdam 2-step
		3	MacAdam 3-step
17 18	Luminous Flux (Lm)	D2	COB D-series Gen.2 level

a) Binning Structure (I_F = 270 mA, T_J = 85 °C)

CRI(R _a) Min.	Nominal CCT(K)	Product Code	V _F Rank	Color Rank	Flux Rank	Flux Range (Φ _v , lm)
	3000	SPHWHAHDNC23YZV3D2	YZ	V3	D2	1428 ~
70	4000	SPHWHAHDNC23YZT3D2	YZ	Т3	D2	1497 ~
	5000	SPHWHAHDNC23YZR3D2	YZ	R3	D2	1545 ~
	2700	SPHWHAHDNC25YZW2D2	· YZ	W2	D2	1275 ~
	2700	SPHWHAHDNC25YZW3D2		W3	D2	1213~
	3000	SPHWHAHDNC25YZV2D2	· YZ	V2	D2	1347 ~
	3000	SPHWHAHDNC25YZV3D2		V3		1047 ~
	3500	SPHWHAHDNC25YZU2D2	· YZ	U2	D2	1386 ~
80		SPHWHAHDNC25YZU3D2	ΥZ	U3	<i>D2</i>	1000 -
	4000	SPHWHAHDNC25YZT2D2	YZ	T2	D2	1419 ~
	4000	SPHWHAHDNC25YZT3D2		Т3	DZ	1415 ~
	5000	SPHWHAHDNC25YZR3D2	YZ	R3	D2	1431 ~
	5700	SPHWHAHDNC25YZQ3D2	YZ	Q3	D2	1431 ~
	6500	SPHWHAHDNC25YZP3D2	YZ	P3	D2	1414 ~
	2700	SPHWHAHDNC27YZW2D2	· YZ	W2	D2	1094 ~
	2700	SPHWHAHDNC27YZW3D2		W3		1004
	3000	SPHWHAHDNC27YZV2D2	· YZ	V2	D2	1146 ~
		SPHWHAHDNC27YZV3D2		V3		
90	3500	SPHWHAHDNC27YZU2D2	· YZ	U2	D2	1182 ~
		SPHWHAHDNC27YZU3D2		U3	<u> </u>	1.02.75
	4000	SPHWHAHDNC27YZT2D2	· YZ	T2	D2	1209 ~
	1 000	SPHWHAHDNC27YZT3D2		Т3	<i>D2</i>	1203 ~
	5000	SPHWHAHDNC27YZR3D2	YZ	R3	D2	1214 ~

b) Chromaticity Region & Coordinates ($I_F = 270 \text{ mA}, T_J = 85 \, ^{\circ}\text{C}$)





	MacAdam Ellipse (W2, W3)										
Step	CIE x	CIE y									
2-step	0.4578	0.4101	53.70	0.0054	0.0028						
3-step	0.4578	0.4101	53.70	0.0081	0.0042						

MacAdam Ellipse (V2, V3)										
Step	CIE x	CIE y								
2-step	0.4338	0.403	53.22	0.0056	0.0027					
3-step	0.4338	0.4030	53.22	0.0083	0.0041					

MacAdam Ellipse (U2, U3)									
Step	CIE x	CIE y							
2-step	0.4073	0.3917	54.00	0.0062	0.0028				
3-step	0.4073	0.3917	54.00	0.0093	0.0041				

	MacAdam Ellipse (T2, T3)										
Step	CIE x	CIE y									
2-step	0.3818	0.3797	53.72	0.0063	0.0027						
3-step	0.3818	0.3797	53.72	0.0094	0.0040						

	MacAdam Ellipse (R3)										
Step	CIE x	CIE y									
3-step	0.3447	0.3553	59.62	0.0082	0.0035						

MacAdam Ellipse (Q3)						
Step	Step CIE x					
3-step	0.3287	0.3417	59.0950	0.0075	0.0032	

MacAdam Ellipse (P3)						
Step	CIE x	CIE y			b	
3-step	0.3123	0.3282	58.5700	0.0067	0.0029	

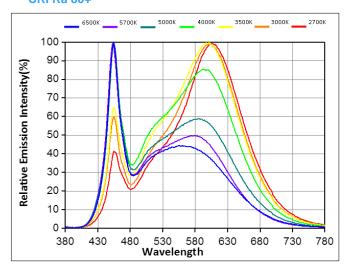
Note:

Samsung maintains measurement tolerance of: Cx, $Cy = \pm 0.005$

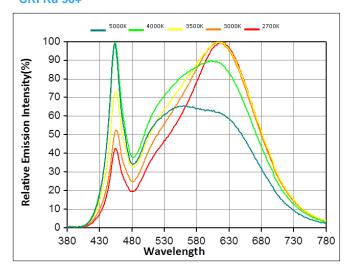
3. Typical Characteristics Graphs

a) Spectrum Distribution ($I_F = 270 \text{mA}, T_J = 85 \text{ }^{\circ}\text{C}$)

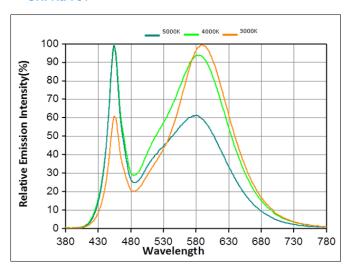
CRI Ra 80+



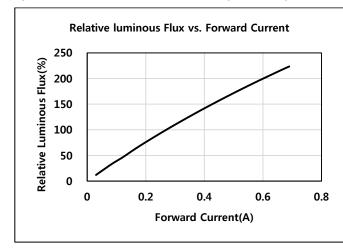
CRI Ra 90+

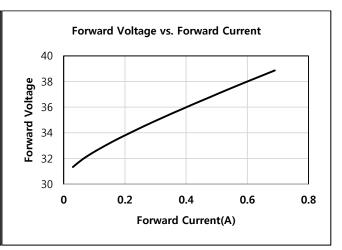


CRI Ra 70+

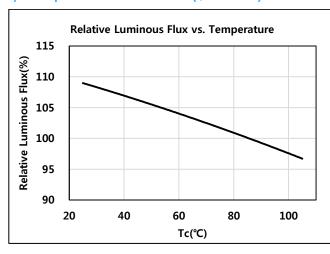


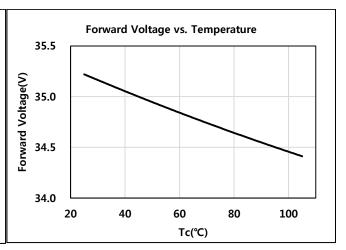
b) Forward Current Characteristics (T_J = 85 °C)



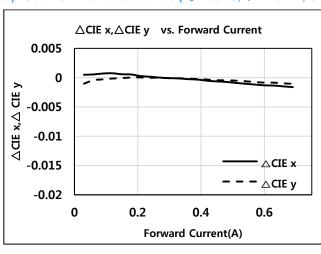


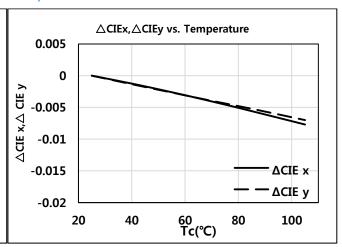
c) Temperature Characteristics(I_F = 270mA)





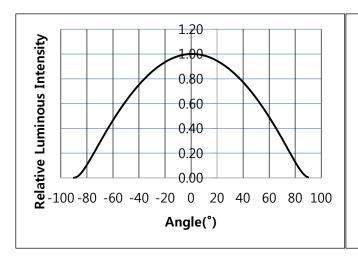
d) Color Shift Characteristics (T_J = 85 °C, I_F =270mA, CRI = 80+)

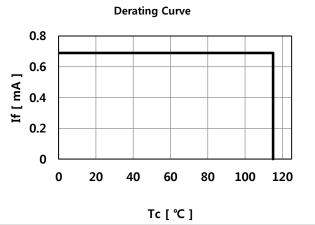




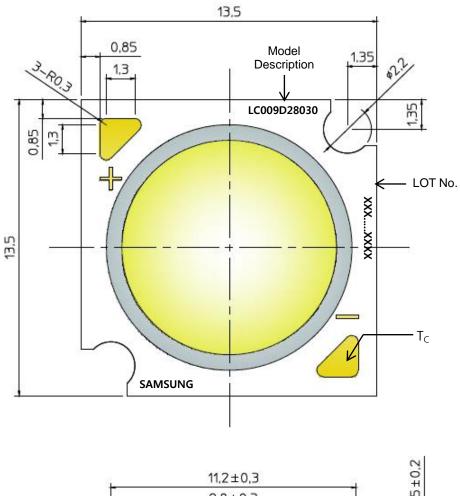
e) Beam Angle Characteristics ($I_F = 270$ mA, $T_J = 85$ °C)

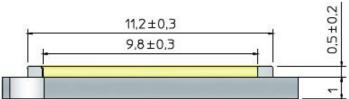
f)Derating Characteristics





4. Outline Drawing & Dimension





1. Unit: mm 2. Tolerance: ± 0.30 mm

ltem	Dimension	Tolerance	Unit
Length	13.5	±0.30	mm
Width	13.5	±0.30	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	9.8	±0.30	mm

Note: Denoted product information above is only an example (LC009D28030 : LC009D, Gen2, CRI80+, 3000K)

5. Reliability Test Items & Conditions

a) Test Items

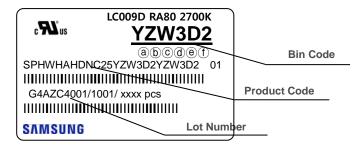
Test Item	Test Condition	Test Hour / Cycle
High Temperature Humidity Life Test	60 °C, 90 % RH,, DC Derating, I _F	1000 h
High Temperature Life Test	85 °C, DC Derating, I _F	1000 h
Low Temperature Life Test	-40 °C, DC, Derating I _F	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Temperature Humidity Storage	60 °C, 90% RH	1000h
TemperatureCycle On/Off Test	-40 °C/ 85 °C each 20 min, 30 min transfer power on/off each 5 min, DC Derating, $I_F = max$	100 cycles
ESD (HBM)	R ₁ : 10 MΩ R ₂ : 1.5 kΩ C: 100 pF	5 times
ESD (MM)	R ₁ : 10 MΩ R ₂ : 0 kΩ C: 200 pF	5 times
Vibration Test	20~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Sulfur Resistance	25 °C, 75%, H2S 15 ppm	504h

b) Criteria for Judging the Damage

ltem	Symbol	Test Condition	nit	
	Зушьог	(T _c = 25 °C)	Min.	Max.
Forward Voltage	V_{F}	I _F = 270 mA	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Φ_{v}	I _F = 270 mA	L.S.L * 0.7	U.S.L * 1.3

6. Label Structure

a) Label Structure



Note: Denoted bincode and product code above is only an example (see description on page 5)

Bin Code:

(a) (refer to page 11)

©d: Chromaticitybin (refer to page 9-10)

(refer to page 6)

b) Lot Number

The lot number is composed of the following characters:



① 3456789 / 1abc / xxxx pcs

1 : Production site (S: Giheung, Korea, G: Tianjin, China)

② : 4(LED)

③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

④ : Year (Z: 2015, A: 2016, B: 2017...)

⑤ : Month (1~9, A, B, C)

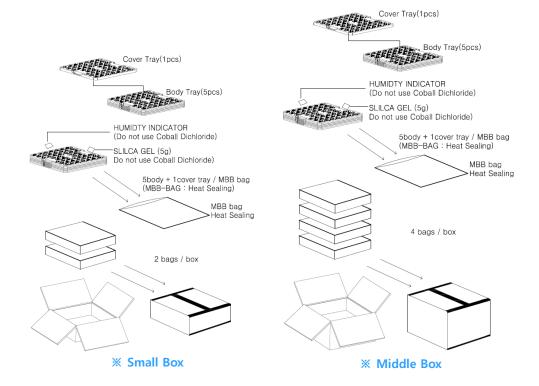
6789 : Day (1~9, A, B~V)

(a) b) c : Product serial number (001 ~ 999)

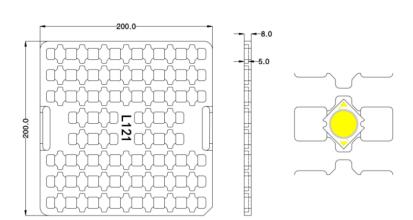
7. Packing Structure

	Max. quantity	Dimension(mm)			
Packing material	in pcs of COB	Length	Width	Height	Tolerance
Tray	50	200	200	8	1
Anti-Static Bag	250 (5 trays)	320	270	-	+/- 0.5
Outer Box	500 (2 bags)	225	225	65	5
Outer Box	1000 (4 bags)	225	225	130	5

a) Packing Structure

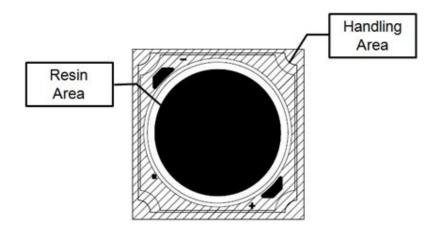


b) Tray



8. Precautions in Handling & Use

- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA
 is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the
 device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 - b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at $23 \pm 5 \degree$ C.
- 6) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system.
 - For more information, please refer to Application Note 'Mechanical & Thermal Guide for COB'.
- 9) In case of drivingLEDsaround the minimum current level (If_min), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



Legal and additional information.

About Samsung Electronics Co., Ltd.

Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies, redefining the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems and semiconductors. We are also leading in the Internet of Things space through, among others, our Digital Health and Smart Home initiatives. We employ 307,000 people across 84 countries. To discover more, please visit our official website at www.samsung.com and our official blog at global.samsungtomorrow.com.

Copyright © 2015 Samsung Electronics Co., Ltd. All rights reserved.

Samsung is a registered trademark of Samsung Electronics Co., Ltd.

Specifications and designs are subject to change without notice. Non-metric weights and measurements are approximate. All data were deemed correct at time of creation. Samsung is not liable for errors or omissions. All brand, product, service names and logos are trademarks and/or registered trademarks of their respective owners and are hereby recognized and acknowledged.

Samsung Electronics Co., Ltd. 95, Samsung 2-ro Giheung-gu Yongin-si, Gyeonggi-do, 446-711 KOREA

www.samsungled.com

